# Designer's™ Data Sheet Complementary NPN-PNP Silicon Power Bipolar Transistor

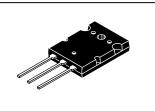
The MJL3281A and MJL1302A are PowerBase power transistors for high power audio, disk head positioners and other linear applications.

- Designed for 100 W Audio Frequency
- Gain Complementary:
- Gain Linearity from 100 mA to 7 A
- High Gain 60 to 175
- h<sub>FE</sub> = 45 (Min) @ I<sub>C</sub> = 8 A
- Low Harmonic Distortion
- High Safe Operation Area 1 A/100 V @ 1 Second
- High f<sub>T</sub> 30 MHz Typical



\*Motorola Preferred Device

15 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 200 VOLTS 200 WATTS



CASE 340G-02, STYLE 2 TO-264

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Rating	Sym	bol	Value	Unit
Collector–Emitter Voltage	VCE	0	200	Vdc
Collector-Base Voltage	VCE	30	200	Vdc
Emitter-Base Voltage	VEE	30	7	Vdc
Collector–Emitter Voltage – 1.5 V	VCE	ΞX	200	Vdc
Collector Current — Continuous — Peak <sup>(1)</sup>	IC	;	15 25	Adc
Base Current — Continuous	۱ <sub>В</sub>	}	1.5	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C Derate Above 25°C	P	)	200 1.43	Watts W/°C
Operating and Storage Junction Temperature Range	Тј, Т	stg	- 65 to +150	°C

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction to Case	R <sub>θ</sub> JC	0.7	°C/W

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^{\circ}C$  unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS				-	
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 100 mAdc, I <sub>B</sub> = 0)	V <sub>CEO(sus)</sub>	200	_	_	Vdc
Emitter–Base Voltage (I <sub>F</sub> = 100 μAdc, I <sub>C</sub> = 0)	VEBO	7	_	_	Vdc

(1) Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

(continued)

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

Designer's is a trademark of Motorola, Inc.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 1



### MJL3281A MJL1302A

#### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•		
Collector Cutoff Current ( $V_{CB} = 200 \text{ Vdc}, I_E = 0$ )	ІСВО	_	_	50	μAdc
Emitter Cutoff Current ( $V_{EB} = 5 \text{ Vdc}, I_{C} = 0$ )	IEBO	_	_	5	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 7 Vdc, I <sub>C</sub> = 0)	IEBO	_	_	25	μAdc
ECOND BREAKDOWN					
Second Breakdown Collector with Base Forward Biased ( $V_{CE} = 50$ Vdc, t = 1 s (non-repetitive) ( $V_{CE} = 100$ Vdc, t = 1 s (non-repetitive)	IS/b	4 1			Adc
ON CHARACTERISTICS			•		
DC Current Gain (I <sub>C</sub> = 100 mAdc, $V_{CE}$ = 5 Vdc) (I <sub>C</sub> = 1 Adc, $V_{CE}$ = 5 Vdc) (I <sub>C</sub> = 3 Adc, $V_{CE}$ = 5 Vdc) (I <sub>C</sub> = 5 Adc, $V_{CE}$ = 5 Vdc) (I <sub>C</sub> = 7 Adc, $V_{CE}$ = 5 Vdc) (I <sub>C</sub> = 15 Adc, $V_{CE}$ = 5 Vdc) (I <sub>C</sub> = 15 Adc, $V_{CE}$ = 5 Vdc)	hfe	60 60 60 60 45 12	125 — — 115 — 35	175 175 175 175 175 	
Collector–Emitter Saturation Voltage $(I_C = 10 \text{ Adc}, I_B = 1 \text{ Adc})$	V <sub>CE(sat)</sub>	_	_	3	Vdc
OYNAMIC CHARACTERISTICS					
Current–Gain — Bandwidth Product (I <sub>C</sub> = 1 Adc, V <sub>CE</sub> = 5 Vdc, f <sub>test</sub> = 1 MHz)	fT	_	30	_	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f <sub>test</sub> = 1 MHz)	C <sub>ob</sub>	_	_	600	pF

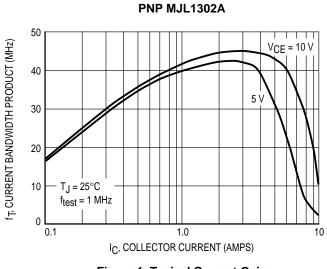


Figure 1. Typical Current Gain Bandwidth Product



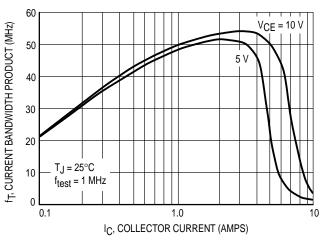


Figure 2. Typical Current Gain Bandwidth Product

## **TYPICAL CHARACTERISTICS**

h<sub>FE</sub>, DC CURRENT GAIN

10

0.1

V<sub>CE</sub> = 20 V

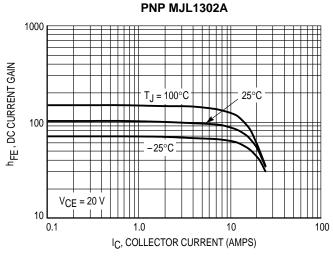
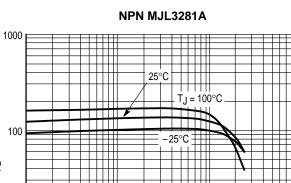


Figure 3. DC Current Gain, V<sub>CE</sub> = 20 V



IC, COLLECTOR CURRENT (AMPS) Figure 4. DC Current Gain, V<sub>CE</sub> = 20 V

1.0

10

100

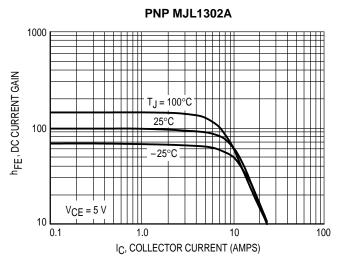


Figure 5. DC Current Gain, VCE = 5 V

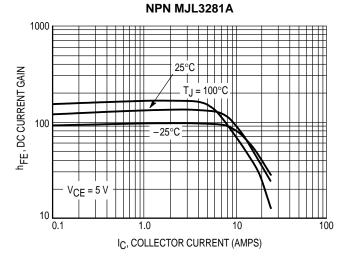
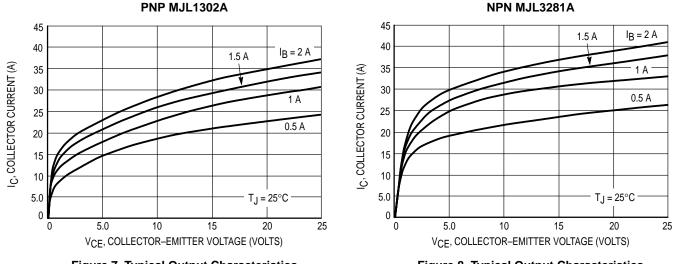


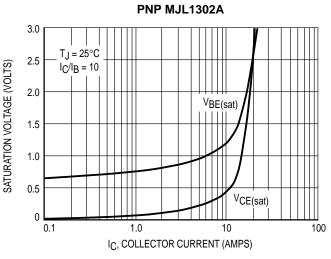
Figure 6. DC Current Gain, VCE = 5 V



**Figure 7. Typical Output Characteristics** 

NPN MJL3281A

#### **TYPICAL CHARACTERISTICS**





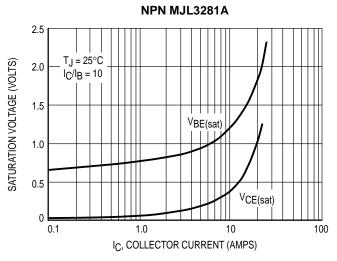


Figure 10. Typical Saturation Voltages

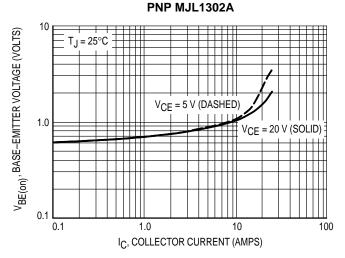


Figure 11. Typical Base–Emitter Voltage

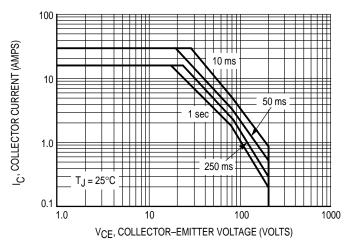


Figure 13. Active Region Safe Operating Area

NPN MJL3281A

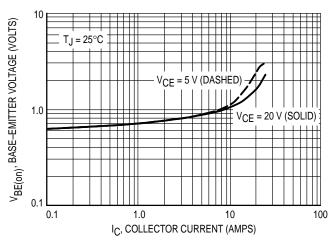


Figure 12. Typical Base–Emitter Voltage

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on  $T_{J(pk)} = 200^{\circ}C$ ; T<sub>C</sub> is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

### MJL3281A MJL1302A

# **TYPICAL CHARACTERISTICS**

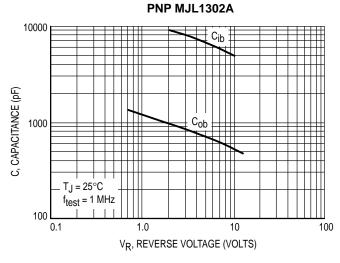
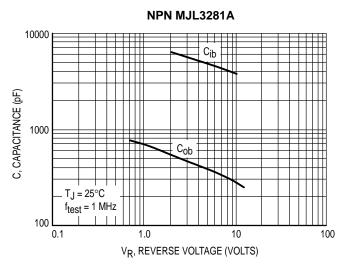
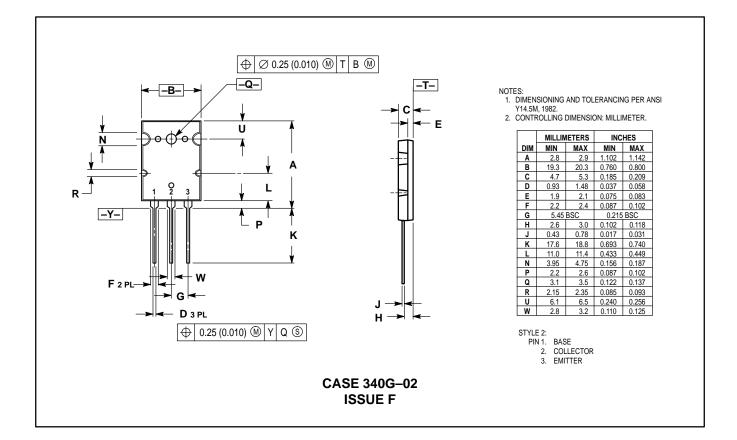


Figure 14. MJL1302A Typical Capacitance







Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and *O* are registered trademarks of Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

#### How to reach us:

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 5405, Denver, Colorado 80217. 1–303–675–2140 or 1–800–441–2447

Customer Focus Center: 1-800-521-6274

 Mfax™: RMFAX0@email.sps.mot.com
 - TOUCHTONE 1-602-244-6609

 Motorola Fax Back System
 - US & Canada ONLY 1-800-774-1848

 - http://sps.motorola.com/mfax/

HOME PAGE: http://motorola.com/sps/



ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298

4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan. 81-3-5487-8488

JAPAN: Nippon Motorola Ltd.; SPD, Strategic Planning Office, 141,

 $\diamond$ 

Mfax is a trademark of Motorola, Inc.